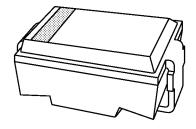
DISCRETE SEMICONDUCTORS

DATA SHEET



US1 series SMA ultra fast low-loss controlled avalanche rectifiers

Product specification

2000 Feb 14





SMA ultra fast low-loss controlled avalanche rectifiers

US1 series

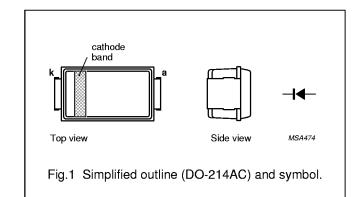
FEATURES

- · Glass passivated
- · High maximum operating temperature
- · Ideal for surface mount automotive applications
- Low leakage current
- · Excellent stability
- · Guaranteed avalanche energy absorption capability
- UL 94V-O classified plastic package
- Shipped in 12 mm embossed tape
- Marking: cathode, date code, type code
- · Easy pick and place.

DESCRIPTION

DO-214AC surface mountable package with glass passivated chip.

The well-defined void-free case is of a transfer-moulded thermo-setting plastic. The small rectangular package has two J bent leads.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage				
	US1A		_	50	V
	US1B		_	100	V
	US1D		_	200	V
	US1G		_	400	V
	US1J		_	600	V
V_{R}	continuous reverse voltage				
	US1A		_	50	V
	US1B		_	100	V
	US1D		_	200	V
	US1G		_	400	V
	US1J		_	600	V
V_{RMS}	root mean square voltage				
	US1A		_	35	V
	US1B		_	70	V
	US1D		_	140	V
	US1G		_	280	V
	US1J		_	420	V
I _{F(AV)}	average forward current	averaged over any 20 ms period; $T_{tp} = 110 ^{\circ}\text{C}$; see Fig.2	_	1	А

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{FSM}	non-repetitive peak forward current	t = 8.3 ms half sine wave; T_j = 25 °C prior to surge; V_R = V_{RRMmax}	_	25	Α
T _{stg}	storage temperature		-65	+175	°C
Tj	junction temperature	See Fig.3	-65	+175	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 1 A;			
	US1A to US1G	see Fig.4	_	1.1	V
	US1J	see Fig.5	_	1.4	V
I _R	reverse current	V _R = V _{RRMmax} ; see Figs 6 and 7	_	10	μΑ
		$V_R = V_{RRMmax}$; $T_j = 165$ °C; see Figs 6 and 7	_	50	μΑ
t _{rr}	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.12	_	50	ns
C _d	diode capacitance	V _R = 4 V; f = 1 MHz;			
	US1A to US1G	see Fig.8	14	_	рF
	US1J	see Fig.9	10	_	pF

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point; see Fig.10		27	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	100	K/W
		note 2	150	K/W

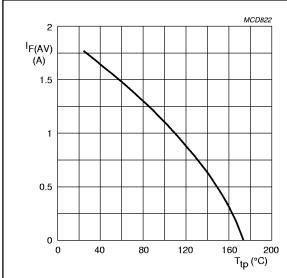
Notes

- 1. Device mounted on Al_2O_3 printed-circuit board, 0.7 mm thick; thickness of copper \geq 35 μ m.
- 2. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper ≥40 μm. For more information please refer to the *'General Part of associated Handbook'*.

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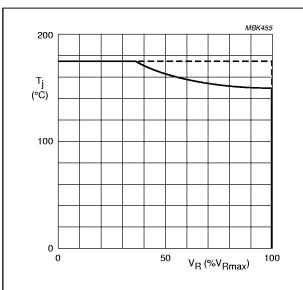
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GRAPHICAL DATA



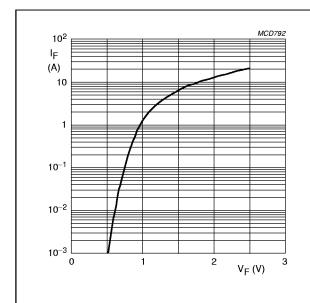
 $V_R = V_{RRMmax}; \, \delta = 0.5; \, a = 1.57.$

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).



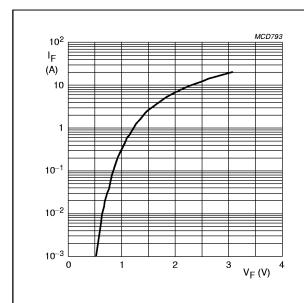
Device mounted as shown in Fig.11. Solid line: Al₂O₃ printed-circuit board. Dotted line: epoxy printed-circuit board.

Fig.3 Maximum permissible junction temperature as a function of reverse voltage.



US1A to G $T_j = 25$ °C.

Fig.4 Forward current as a function of forward voltage; typical values.



US1J $T_i = 25$ °C.

Fig.5 Forward current as a function of forward voltage; typical values.

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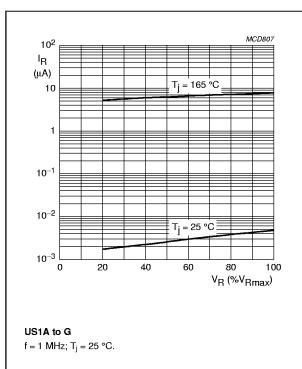


Fig.6 Reverse current as a function of reverse voltage; typical values.

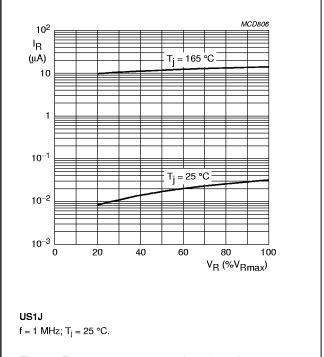


Fig.7 Reverse current as a function of reverse voltage; typical values.

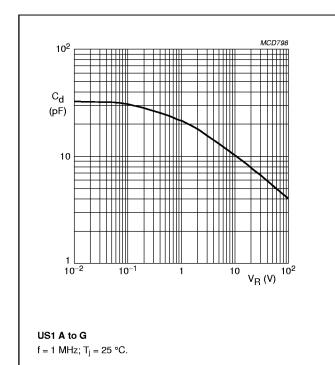
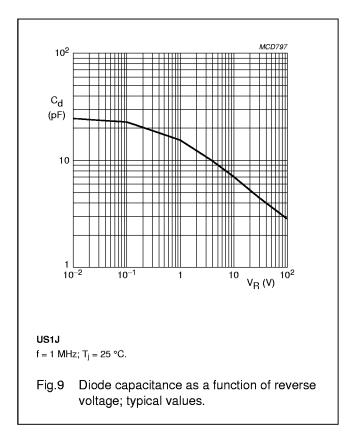


Fig.8 Diode capacitance as a function of reverse voltage; typical values.



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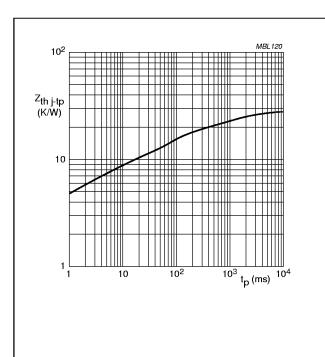
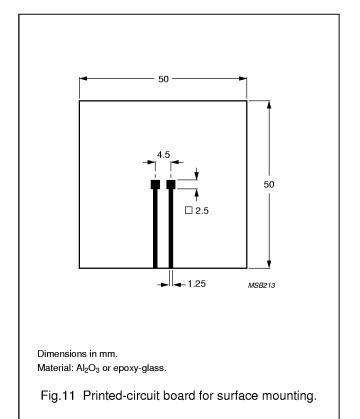
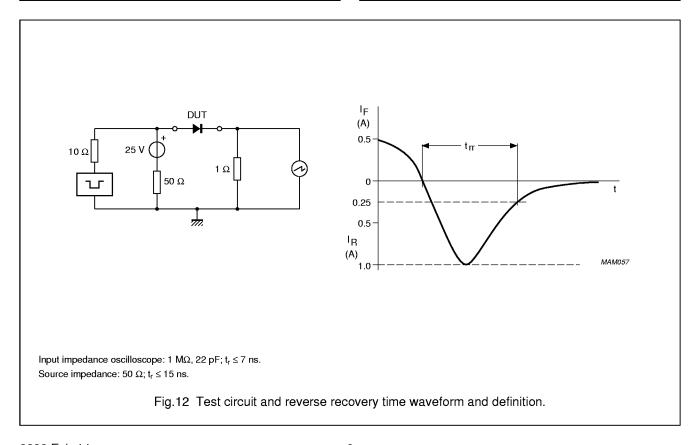


Fig.10 Transient thermal impedance as a function of pulse width.





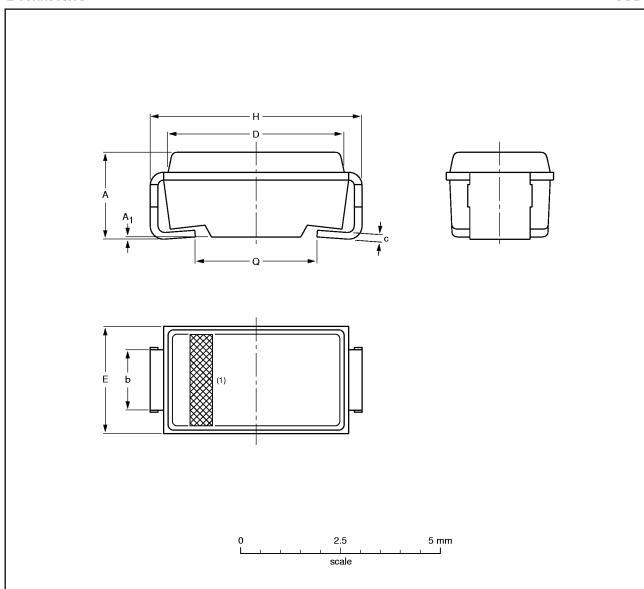
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PACKAGE OUTLINE

Transfer-moulded thermo-setting plastic small rectangular surface mounted package; 2 connectors

SOD124



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁	b	O	D	E	н	Q
mm	2.3 2.0	0.05	1.6 1.4	0.2	4.5 4.3	2.8 2.4	5.5 5.1	3.3 2.7

Note

 $1. \ The \ marking \ band \ indicates \ the \ cathode.$

OUTLINE		REFER	EUROPEAN ISSUE DA				
VERSION	IEC	JEDEC EIA.	EIAJ		PROJECTION	ISSUE DATE	
SOD124		DO-214AC				99-10-22	

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.